L Number	Hits	Search Text	DB	Time stamp
22	4210514	@pd>20020514	USPAT;	2004/07/21 18:41
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
23	1	118/\$.ccls. and ((illuminat\$ near5 visual) same	USPAT;	2004/07/21 18:41
1		(semiconductor))	US-PGPUB;	
-			EPO; JPO;	
			DERWENT;	
24	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness) and	IBM_TDB	2004/07/04 40:44
[ - '		(photoresist)	USPAT; US-PGPUB;	2004/07/21 18:41
	1	(priotoriosist)	EPO; JPO;	
			DERWENT;	
	ļ		IBM TDB	
25	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness)	USPAT;	2004/07/21 18:41
		, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	2004/01/21 10.41
			EPO; JPO;	
			DERWENT.	
			IBM_TDB	
26	397	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness)	USPAT;	2004/07/21 18:41
İ			US-PGPUB;	
			EPO; JPO;	Ì
1			DERWENT;	
27	E400	(440/200 I 440/200 I	IBM_TDB	
21	5122	(118/320.ccls. or 118/326.ccls. or 118/712.ccls. or	USPAT;	2004/07/21 18:41
	}	118/713.ccls. or 118/501.ccls. or 118/500.ccls.)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
28	4083	(222/113.ccls. or 362/231.ccls. or 355/53.ccls. or	IBM_TDB USPAT;	2004/07/21 18:41
		355/70.ccls. or 396/611.ccls.)	US-PGPUB;	2004/07/21 10.41
		,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
29	3708	156/379.ccls. or 427/8.ccls. or 427/9.ccls. or 427/10.ccls. or	USPAT;	2004/07/21 18:41
1		427/240.ccls. or 427/425.ccls.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	454000		IBM_TDB	
30	451303	process and chamber andnon-reflective and 118/\$.ccls.	USPAT;	2004/07/21 18:41
1			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
31	4557	(362/145.ccls. or 362/147.ccls. or 362/149.ccls. or	IBM_TDB USPAT;	2004/07/21 18:41
	.50,	362/154.ccls. or 362/155.ccls. or 362/800,ccls. or	US-PGPUB:	2004/07/21 18:41
	}	362/803.ccls. or 362/458.ccls. or 362/253.ccls.)	EPO; JPO;	
<u> </u>			DERWENT;	
			IBM TDB	
32	174	118/677	USPAT;	2004/07/21 18:41
			US-PGPUB;	
			EPO; JPO;	ľ
			DERWENT;	
		(440(7401-) - 1 CP - 1 - 1	IBM_TDB	
33	1	(118/713.ccls.) and (illumination near3 intensity)	USPAT;	2004/07/21 18:41
			US-PGPUB;	Ī
	1		EPO; JPO;	
		İ	DERWENT;	
L	<u>-</u>		IBM_TDB	

			,	
34	2168	356/\$.ccls. and (illuminat\$4 near3 intens\$4)	USPAT;	2004/07/21 18:41
			US-PGPUB;	
	ľ		EPO; JPO;	
1			DERWENT,	
			IBM TDB	
72	9851	"advanced micro devices"	USPAT;	2004/07/21 18:42
			US-PGPUB	200 1101121 10.42
81	2594	250/205	USPAT;	2004/07/21 18:42
			US-PGPUB:	2004/01/21 10.42
1			EPO; JPO;	
			DERWENT;	
83	112	((250/205).CCLS.) and (coating or dispensing or coat or	IBM_TDB	0004/07/04 40 40
00	112	dispense)	USPAT;	2004/07/21 18:43
		dispense)	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT;	
			IBM_TDB	
21	965	subramanian.in.	USPAT;	2004/07/21 18:43
1			US-PGPUB	
35	339	@pd>20020514 and (118/50.ccls. or 118/52.ccls. or	USPAT;	2004/07/21 18:43
		118/50.1.ccls. or 118/56.ccls. )	US-PGPUB;	
		·	EPO; JPO;	
			DERWENT:	
			IBM_TDB	
36	626	@pd>20020514 and (118/320.ccls. or 118/326.ccls. or	USPAT;	2004/07/21 18:44
		118/712.ccls. or 118/713.ccls. or 118/501.ccls. or	US-PGPUB:	2007/01/21 10.44
		118/500.ccls.)	EPO; JPO;	
	1 1	1107000.0010.7	DERWENT;	
			1	1
37	1351	@pd>20020514 and (222/113.ccls. or 362/231.ccls. or	IBM_TDB	0004/07/04 40 44
0,	1001	355/53.ccls. or 355/70.ccls. or 396/611.ccls.)	USPAT;	2004/07/21 18:44
		333/33.ccis. of 333/70.ccis. of 390/011.ccis.)	US-PGPUB;	
			EPO; JPO;	
	1 1		DERWENT;	
38	500	On the 00000544	IBM_TDB	
36	588	@pd>20020514 and (156/379.ccls. or 427/8.ccls. or	USPAT;	2004/07/21 18:45
		427/9.ccls. or 427/10.ccls. or 427/240.ccls. or 427/425.ccls.)	US-PGPUB;	
			EPO; JPO;	]
			DERWENT;	
			IBM_TDB	
39	1001	@pd>20020514 and (362/145.ccls. or 362/147.ccls. or	USPAT;	2004/07/21 18:45
		362/149.ccls. or 362/154.ccls. or 362/155.ccls. or	US-PGPUB;	
		362/800.ccls. or 362/803.ccls. or 362/458.ccls. or	EPO; JPO;	
		362/253.ccls.)	DERWENT;	
İ	1	,	IBM_TDB	
40	17	118/\$.ccls. and ((visual near3 inspection) same (chuck or	USPAT;	2004/07/21 18:45
	]	holder or table))	US-PGPUB:	
f		"	EPO; JPO;	
			DERWENT;	
	]		IBM_TDB	
41	11	118/\$.ccls. and ((visual near3 inspection) same	USPAT;	2004/07/24 40:45
' '	''	(semiconductor))		2004/07/21 18:45
		(Someonia dotor))	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT;	
42	97	118/\$ cole and //illuminat© acres /	IBM_TDB	000440745
72	9/	118/\$.ccls. and ((illuminat\$) same (semiconductor))	USPAT;	2004/07/21 18:45
			US-PGPUB;	
			EPO; JPO;	İ
			DERWENT;	
	, ,	44040	IBM_TDB	
43	191	118/\$.ccls. and ((illuminat\$) same (chamber))	USPAT;	2004/07/21 18:45
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	

44	717	1	USPAT;	2004/07/21 18:45
		or "light emitting diodes") and controller	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
45	1	"5843527".PN.	USPAT	2004/07/21 18:45
46	222		USPAT;	2004/07/21 18:45
	İ	or "light emitting diodes") and (controller same (input or	US-PGPUB;	200 1/0//21 10.40
		output))	EPO; JPO;	
		- Surpary	DERWENT;	
1				
47	1	6122042.pn.	IBM_TDB	0004/07/04 40 45
48	'		USPAT	2004/07/21 18:45
49		6122042.pn. and (coat or coating)	USPAT	2004/07/21 18:45
49	61	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness)	USPAT;	2004/07/21 18:45
		and photoresist	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
50	50	(118/\$.ccls.) and (photodiode) and (thickness) and controller	USPAT;	2004/07/21 18:46
	1		US-PGPUB;	
1	1		EPO; JPO;	
1			DERWENT;	
1			IBM_TDB	
51	11	"5985357"	USPAT	2004/07/21 18:46
52	97	process and chamber and anti-reflective and 118/\$.ccls.	USPAT;	2004/07/21 18:46
		process and sharmon and and renestive and 110/4.0015.	US-PGPUB;	2004/01/21 10.40
			EPO; JPO;	
1			DERWENT;	
	İ			
53	1	4712140 nn	IBM_TDB	0004/07/04 40 40
54	1 1	4713140.pn.	USPAT	2004/07/21 18:46
1	1	4696209.pn.	USPAT	2004/07/21 18:46
55	1	4227347.pn.	USPAT	2004/07/21 18:46
56	13	process and chamber and non-reflective and 118/\$.ccls.	USPAT;	2004/07/21 18:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
57	4	process and chamber and nonreflective and 118/\$.ccls.	USPAT;	2004/07/21 18:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT	
			IBM TDB	
58	1569	438/16	USPAT;	2004/07/21 18:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
59	162	438/16 and reflectivity		2004/07/04 40:40
33	102	100/10 and renectivity	USPAT;	2004/07/21 18:46
			US-PGPUB;	
			EPO; JPO;	
	[		DERWENT;	
		40040	IBM_TDB	
60	23	438/16 and (illumination near3 intensity)	USPAT;	2004/07/21 18:46
			US-PGPUB;	
	j		EPO; JPO;	
			DERWENT,	
1			IBM_TDB	
61	28	438/16 and (illuminat\$4 near3 intens\$4)	USPAT;	2004/07/21 18:46
			US-PGPUB;	
	]		EPO; JPO;	
			DERWENT;	
			IBM TDB	
L	<u> </u>		מטו_וטוטו	

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62	5	(118/712.ccls.) and (illumination near3 intensity)	USPAT; US-PGPUB;	2004/07/21 18:46
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
63	679	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and	USPAT;	2004/07/21 18:47
	•	semiconductor	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
64	347	256/9 pole and /illuminat@4 mage2 interac@4) and	IBM_TDB	
04	347	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and semiconductor and thickness	USPAT;	2004/07/21 18:47
1		Serificonductor and thickness	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
65	18	"6016562"	IBM_TDB USPAT	2004/07/24 40:47
66	1398	((118/712) or (118/713)).CCLS.	USPAT;	2004/07/21 18:47
	1000	((110/112) 01 (110/110)).0020.	US-PGPUB;	2004/07/21 18:47
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
67	1	("6031607").PN.	USPAT	2004/07/21 18:47
68	8	356/\$.ccls. and (adjustable near3 intens\$4) and	USPAT;	2004/07/21 18:48
		semiconductor and thickness	US-PGPUB:	===
			EPO; JPO;	
			DERWENT:	
			IBM_TDB	
69	26	356/\$.ccls. and (adjustable near3 illuminat\$4) and	USPAT;	2004/07/21 18:48
		semiconductor and thickness	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
70	88	356/\$.ccls. and (variable near3 intens\$4) and	USPAT;	2004/07/21 18:48
İ		semiconductor and thickness	US-PGPUB;	
			EPO; JPO;	
İ			DERWENT;	
71	1	("6376013").PN.	IBM_TDB	2224/27/24 42 42
73	165	subramanian.in. and (advanced near2 micro)	USPAT	2004/07/21 18:48
/ 0	103	subramanian.in. and (advanced flear2 ffilcto)	USPAT;	2004/07/21 18:48
74	7444	advanced.asn. and micro.asn. and devices.asn.	US-PGPUB USPAT:	2004/07/04 40:54
1	'	aavanoos.son. and inicio.aon. and devices.aon.	US-PGPUB	2004/07/21 18:51
75	154	advanced.asn. and micro.asn. and devices.asn. and	USPAT;	2004/07/21 18:51
		(396/\$.ccls. or 118/\$.ccls. or 427/\$.ccls. or 131/\$.ccls.)	US-PGPUB	2007/01/21 10.31
76	8	(("5968268") or ("5845170") or ("5720814") or ("5718992") or	USPAT	2004/07/21 18:51
		("5393624") or ("5366757") or ("5127362") or	''''	====5
		("5089305")).PN.		
77	14	(("5962070") or ("5942037") or ("5885755") or ("5885661") or	USPAT	2004/07/21 18:51
	1	("5826130") or ("5820677") or ("5678116") or ("5625433") or		
	]	("5555234") or ("5474877") or ("5275658") or ("5089305") or		
1		("4997552") or ("4564280")).PN.		,
78	1 1	"20020029744"	US-PGPUB	2004/07/21 18:51
79	10	356/\$.ccls. and (compensation near3 illuminat\$4) and	USPAT;	2004/07/21 18:51
1	]	semiconductor and thickness	US-PGPUB;	
			EPO; JPO;	
İ	[		DERWENT;	
80	97	356/455	IBM_TDB	0004/0=:=:
1 00	] 9/	356/455	USPAT;	2004/07/21 18:51
			US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
	<u> </u>		IBM_TDB	

82	69	(356/455).CCLS.	USPAT;	2004/07/21 18:51
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
84	127	((250/205).CCLS.) and (coating or dispensing or coat or	USPAT;	2004/07/21 18:51
		dispense)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
85	1214	(250/205).CCLS.	USPAT;	2004/07/21 18:52
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
L			IBM_TDB	